2018
( Pre-CBCS )
( 3rd Semester )

## ELECTRONICS

THIRD PAPER
( Electronic Devices and Amplifiers )
Full Marks : 55
Time : $2^{1 ⁄ 2}$ hours
(PART : A—OBJECTIVE )
( Marks : 20 )
The figures in the margin indicate full marks for the questions

> SECTION—A
> ( Marks : 5 )

Tick $(\checkmark)$ the correct answer in the brackets provided :
$1 \times 5=5$

1. The drain-source voltage above which drain current becomes constant is known as $\qquad$ voltage.
(a) saturation
( )
(b) pinch-off
(c) active
( )
(d) cut-off
2. The control element in an SCR is
(a) cathode ( )
(b) anode
(d) gate
3. A $p-n$ junction that radiates energy as light instead of heat is called a/an
(a) LED ( )
(b) photo-diode
(c) pin diode
(d) Zener diode
4. The maximum overall efficiency of a class-B push-pull amplifier is
(a) $50 \%$
(c) $78.5 \%$

(b) $25 \%$
(d) $85 \%$
5. The common-mode gain is
(a) very high ( )
(b) very low ( )
(c) always unity ( )
(d) unpredictable ( )

SECTION-B
( Marks : 15 )
Answer any five questions of the following :

1. For an $n$-channel JFET, $I_{D S S}=8.7 \mathrm{~mA}, V_{p}=-3 \mathrm{~V}$ and $V_{G S}=-1 \mathrm{~V}$. Find $I_{D}$ and $g_{m}$.
2. Explain $90^{\circ}$ phase control of an SCR.
3. Discuss the construction of solar cell with a neat diagram.
4. Write the relation between quality factor and bandwidth of a tuned amplifier. The $Q$-value of a tuned amplifier is 60 . If the resonant frequency for the amplifier is 1200 kHz , find (a) bandwidth and (b) cut-off frequency.
5. Explain the working of an operational amplifier in inverting configuration.
6. What are the advantages of inserting an intrinsic layer in a $p-n$ junction diode to form a PIN diode?
7. The following readings were obtained experimentally from a JFET :

| $V_{G S}$ | 0 V | 0 V | -0.2 V |
| :---: | :---: | :---: | :---: |
| $V_{D S}$ | 7 V | 15 V | 15 V |
| $I_{D}$ | 10 mA | 10.25 mA | 9.65 mA |

Determine (a) a.c. drain resistance, (b) transconductance and (c) amplification factor.
8. Write a short note on UJT relaxation oscillator.

## (PART : B—DESCRIPTIVE )

( Marks: 35 )
The figures in the margin indicate full marks for the questions

1. (a) Why is JFET called a unipolar transistor? Explain the main parameters of a JFET.
(b) For a certain D-MOSFET, $I_{D S S}=10 \mathrm{~mA}$ and $V_{G S(\text { off })}=-8 \mathrm{~V}$.
(i) Is this an $n$-channel or a $p$-channel?
(ii) Calculate $I_{D}$ at $V_{G S}=-3 \mathrm{~V}$.
(iii) Calculate $I_{D}$ at $V_{G S}=+3 \mathrm{~V}$.

## OR

2. (a) Describe the construction and working principle of enhancement mode MOSFET and give some applications of MOSFET. $2+2+1=5$
(b) Define the conventional drain current in FET. On what factor does it depend?
$1+1=2$
3. (a) Describe the operation of Silicon Controlled Rectifier (SCR). How will you explain this operation using two-transistor analogy? 3+2=5
(b) What is dynamic resistance of junction diode? Give the condition for linearity of the junction diode.

## OR

4. (a) Write the construction and operation of UJT for the cases (i) when emitter is open and (ii) when positive voltage applied to the emitter.
(b) Explain with diagram, the $V-I$ characteristics of $p-n$ junction diode in forward bias and reverse bias.
5. (a) Write down the theory and construction of Light Emitting Diode (LED).
(b) How is population inversion created in semiconductor laser?

## OR

6. (a) With a neat diagram, explain the construction and working of a $p-n$ junction photodiode.
(b) Explain how Zener diode can be used as voltage regulator.
7. (a) With a neat diagram, explain the working of single-tuned amplifier. Discuss its frequency response.
(b) Define the crossover distortion in class-B push-pull amplifier.

## OR

8. (a) What are power amplifiers? Show that the efficiency of transformer coupled class-A amplifier is $50 \%$ in an ideal case.
(b) Mention some special characteristics that distinguish a tuned amplifier from other amplifiers.
9. (a) Derive an expression for the overall gain in an OP-AMP in the case of non-inverting configuration. The non-inverting OP-AMP has $R_{f}=5 \mathrm{k} \Omega$ and $R_{l}=1 \mathrm{k} \Omega$. Calculate the voltage gain.
$4+1=5$
(b) A differential amplifier has an open-circuit voltage gain of 100. The input signals are 3.25 V and 3.15 V . Determine the output voltage.

## OR

10. (a) With the help of a circuit diagram, explain the operation of a balanced differential amplifier.
(b) Why is the 'summing point' of the operational amplifier (OP-AMP) called 'virtual ground'?
